

3875081 G E SOLID STATE

01E 17554 D T-33-11  
Pro Electron Power Transistors

File Number 1242

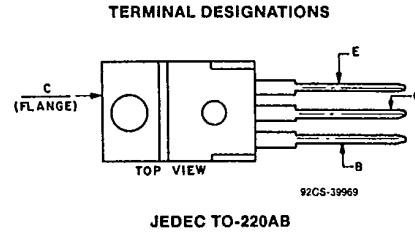
BD795, BD796, BD797, BD798,  
BD799, BD800, BD801, BD802

## Epitaxial-Base, Silicon N-P-N and P-N-P VERSAWATT Transistors

General-Purpose Medium-Power Types for  
Switching and Amplifier Applications

**Features:**

- Low saturation voltages
- Complementary n-p-n and p-n-p types
- Maximum safe-area-of-operation curves



The RCA-BD795, BD797, BD799, and BD801 n-p-n transistors and their p-n-p complements BD796, BD798, BD800, and BD802, respectively, are epitaxial-base silicon types intended for a wide variety of medium-power switching and amplifier applications, such as series and shunt regulators and driver and output stages of high-fidelity amplifiers.

These transistors are supplied in the JEDEC TO-220AB (VERSAWATT) plastic package.

**MAXIMUM RATINGS, Absolute-Maximum Values:**

	N-P-N	BD795	BD797	BD799	BD801	
	P-N-P	BD796*	BD798*	BD800*	BD802*	
$V_{CBO}$ .....		45	60	80	100	V
$V_{CEO(SUS)}$ .....		45	60	80	100	V
$V_{EBO}$ .....				5		V
$I_C$ .....				8		A
$I_B$ .....				3		A
$P_T$ .....				65		W
$T_C \leq 25^\circ C$ .....				Derate Linearly 0.522		W/°C
$T_C > 25^\circ C$ .....				-55 to 150		°C
$T_{stg}$ $T_J$ .....						°C
$T_L$ At distances $\geq 1/8$ in. (3.17 mm) from case for 10 s max. ....				235		°C

\*For p-n-p devices, voltage and current values are negative.

**BD795, BD796, BD797, BD798,  
BD799, BD800, BD801, BD802**

**ELECTRICAL CHARACTERISTICS, at Case Temperature ( $T_C$ ) = 25°C  
Unless Otherwise Specified**

CHARACTERISTIC	TEST CONDITIONS					LIMITS				UNITS
	VOLTAGE V dc			CURRENT A dc		BD795 BD796 ●		BD797 BD798 ●		
	$V_{CB}$	$V_{CE}$	$V_{BE}$	$I_C$	$I_B$	Min.	Max.	Min.	Max.	
$I_{CBO}$	45 60					—	0.1	—	—	mA
$I_{EBO}$			-5	0		—	1	—	1	
$V_{CE0}^b$				0.1 <sup>a</sup>	0	45	—	60	—	V
$h_{FE}$		2 <sup>c</sup> 2		1 <sup>a</sup> 3 <sup>a</sup>		40 25	—	40 25	—	
$V_{BE(ON)}$		2		3 <sup>a</sup>		—	1.6	—	1.6	V
$V_{CE(sat)}$				3 <sup>a</sup>	0.3	—	1	—	1	
$f_T$ $f = 1$ MHz		10		0.25		3	—	3	—	MHZ
$R_{\theta JC}$						—	1.92	—	1.92	°C/W

<sup>a</sup> Pulsed; Pulse duration = 300  $\mu$ s, duty factor = 1.8%.

<sup>b</sup> CAUTION: The sustaining voltage  $V_{CE0(sus)}$  *MUST NOT* be measured on a curve tracer.

<sup>c</sup> For p-n-p devices, voltage and current values are negative.

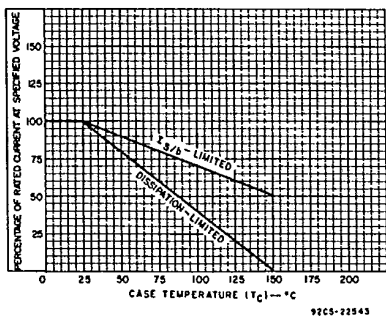


Fig. 1—Current derating curves for all types.

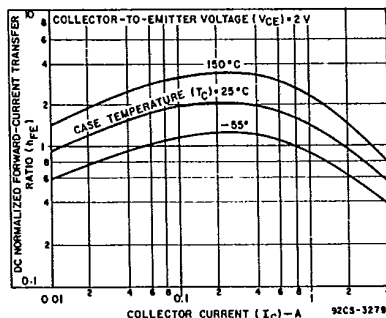


Fig. 2—Normalized dc-beta characteristics for all types.

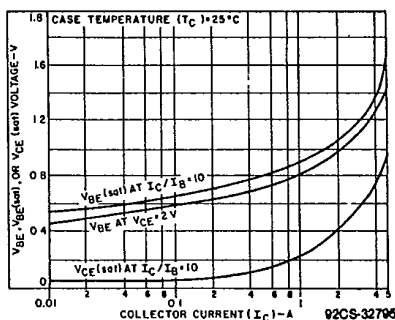


Fig. 3—Typical "on" voltage characteristics for all types.

**BD795, BD796, BD797, BD798,  
BD799, BD800, BD801, BD802**

**ELECTRICAL CHARACTERISTICS, at Case Temperature ( $T_C$ ) = 25°C**  
Unless Otherwise Specified

T-33-21

CHARACTERISTIC	TEST CONDITIONS					LIMITS				UNITS
	VOLTAGE			CURRENT		BD799 BD800 •		BD801 BD802 •		
	$V_{CB}$	$V_{CE}$	$V_{BE}$	$I_C$	$I_B$	Min.	Max.	Min.	Max.	
$I_{CBO}$	80 100					—	0.1	—	—	mA
$I_{EBO}$			-5	0		—	1	—	1	
$V_{CE0}^b$				0.1 <sup>a</sup>	0	80	—	100	—	V
$h_{FE}$		2		1 <sup>a</sup>		30	—	30	—	
		2		3 <sup>a</sup>		15	—	15	—	
$V_{BE(ON)}$		2		3 <sup>a</sup>		—	1.6	—	1.6	V
$V_{CE(sat)}$				3 <sup>a</sup>	0.3	—	1	—	1	
$t_T$ $f = 1$ MHz		10		0.25		3	—	3	—	MHZ
$R_{\theta JC}$						—	1.92	—	1.92	°C/W

- <sup>a</sup> Pulsed; Pulse duration = 300  $\mu$ s, duty factor = 1.8%.
- <sup>b</sup> CAUTION: The sustaining voltage  $V_{CE0(sus)}$  **MUST NOT** be measured on a curve tracer.
- For p-n-p devices, voltage and current values are negative.

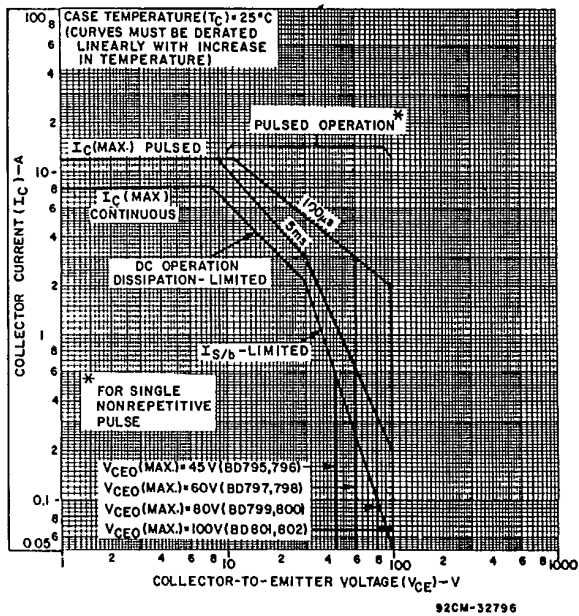


Fig. 4 — Maximum operating areas for all types.

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